FORM PTO-1449 (REV.7-80)	· · · · · · ·	U.S. PAT	ATTY. DOCKET NO. 854063.552D1		APPLICATION NO.					
				APPLICANTS  Cabriele Parlecabi et al						
	[M	FORMATION DISCLOSURE (Use several sheets if nec		Gabriele Barlocchi et al.  FILING DATE GROUP ART UNIT						
(Ox section sheet)					September 18, 2003	GROUP ART ONLY				
U.S. PATENT DOCUMENTS										
•EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME		CLASS		SUBCLASS	FILING IF APPRO	DATE PRIATE
FE	AA	4,579,621	04/01/86	Hine		156		612		
P8.	AB	4,993,143	02/19/91	Sidner et al.		29		621.1		
P	AC	5,659,138	08/19/97	Iwata et al.		73		514.33		
Po	AD	5,883,420	03/16/99	Mirza et al.		257		419		
R	AE	5,926,721	07/20/99	Hong et al.		438		413		
Pr	AF	5,889,872	03/30/99	Sooriakumar et al.		381		174		
Pr.	AG	6,093,330	07/25/00	Chong et al.		216		2		
Po	АH	6,180,480	01/30/01	Economikos et al.		438		386		
R	Al	6,307,247	10/23/01	Davies		257		522	_	
	Ą					<u> </u>				
FOREIGN PATENT DOCUMENTS										
		DOCUMENT NUMBER	DATE	COUNTRY					TRANSI	ATION NO
R	AK	JP4114470	04/15/92	Japan (+abstract)						
Pr	AL	JP9082983	03/28/97	Japan						
	AM									
	AN									
	ΑO									
OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)										
P <sub>C</sub>	P Tabata, Osamu et al., "Anisotropic etching of silicon TMAH solutions", Sensors and									
0		Actuators, July 1992. Pages 51-57.								
R	AQ	Kovacs, Gregory T. A. et al., "Bulk Micromachining of Silicon", IEEE, August 1998. Vo. 86, No. 8, Pages 1536-1551.								
-	AR	00,110.0,1 agos 1550-1551.								
EXAMINE		7	<del> </del>	<del></del>	DATE CONSIDERED			-		
1/1/h 45th troth 3114/03										
* EXAMPLER: Initial if reference considered, whether or not criteria is in conformance with MPEP 609. Draw line through citation if not in										